

# SPECIFICATION

							IS	ISSUED DATE: 2015. 09. 21			
							D	OCUMEN	T NO: KPDC-KO	CL5685S-0	
CUSTON	/IER :				-						
DESCRI	PTION	l : <b>850</b> nm	IrED		-						
MODEL	NO. : I	KCL5685	s		_						
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				PRODUCTION		Q/A					
		ISSUE	REVIEW	APPR'L	REVIEW	APPR'L	REVIEW	APPR'L			
		[ CUSTOMER APPROVAL ]									
		ISSUE	REVIEW								
	[RE	VISION	]								
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	01	15.09.21		ı	ssue		E	C. Jung	HJ.Lee		



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AUK takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet.

Please obey the instructions mentioned below for actual use of this device.

- 1) This device is designed for general electronic equipment.

  Main use of this device are as follows;
  - \* Computer \* OA equipment \* Telecommunication equipmet(Terminal)
  - \* Measuring instrument \* Machine tool \*Industrial robot
  - \* AV equipment \* Home appliance, etc.
- ② Please take proper steps in order to maintain reliability and safety, in case this device is used for the uses mentioned below which require high reliability.
  - \* Unit concerning control and safety of a vehicle (air plane,train,automobile etc.)
  - \* Traffic signal \* Gas leak detection breaker
  - \* Fire box and burglar alarm box \* Other safety equipment, etc.
- ③ Please don't use for the uses mentioned below which require extremely high reliability.
  - \* Space equipment \* Telecommunication equipment(Trunk)
  - \* Nuclear control equipment \* Medical equipment(relating to any fatal element),etc.



#### 1. Description

The KCL5685S is GaAlAs infrared emitting diode that is designed for high power, low forward voltage. This device is optimized for speed and efficiency at emission wavelength 850nm and has a high radiant efficiency over a wide range of forward current.

#### 2. Features

- ◆ 850nm wavelength
- ♦ High speed : 25ns rise time
- High power and high reliability
- ◆ Available for pulse operating

### 3. Applications

- ◆ Emitter of IrDA
- ♦ IR communication
- Optical Switch
- ◆ Available for Wireless Digital Data Transmission

## 4. Package Outline

8.7 Min24.0

1.0 Ø5.0 Ø5.8

Q Cathode

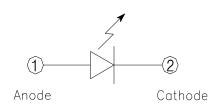
Max1.3 Resin Over

1. GENERAL TOLERANCE : ± 0.2

[Unit: mm]

THICKNESS: 0.5mm
 PIN CONFIGURATION

NOTE





5. Absolute Maximum Ratings

[Ta=25°C]

7 110 0 0 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1			
Parameter	Symbol	Rating	Unit
Power Dissipation	P <sub>D</sub>	150	mW
Forward Current	I <sub>F</sub>	100	mA
Pulse forward current *1	I <sub>FP</sub>	1.0	Α
Reverse Voltage	$V_R$	4.0	V
Operating Temperature *2	T <sub>opr.</sub>	-25 ~ +85	°C
Storage Temperature *2	T <sub>stg.</sub>	-30 ~ +100	°C
Soldering Temperature *3	T <sub>sol.</sub>	260	°C

<sup>\*1.</sup> Duty ratio=1/100, pulse width=0.1ms

## 6. Electro-Optical Characteristics

[Ta=25℃]

Paramo	eter	Symbol	Conditions	Min.	Тур.	Max.	Unit.
Forward voltage		VF	I <sub>F</sub> =50mA		1.5	2.0	V
Reverse current		lr	V <sub>R</sub> =5V			10	μA
Radiant intensity		le	I <sub>F</sub> =50 <sup>mA</sup> 30				mW/sr
Peak emission wave	length	λр	I <sub>F</sub> =50mA		850		nm
Spectral bandwidth 5	50%	$\triangle \lambda$	I <sub>F</sub> =50mA		45		nm
Switching Speeds	Rise time	tr	-		25		ns
Switching Speeds	Fall time	tf	-		13		ns
Half angle	-	△θ	I <sub>F</sub> =50mA		±15		deg.
Cut off frequency *4		fc	I <sub>F</sub> =50 <sup>mA</sup> DC +10 <sup>mA</sup> p-p		14		MHz

<sup>\*4.</sup>  $10\log Po(fc MHz)/Po(0.1 MHz) = -3$ 

## 7. Inspection Criteria

7-1. In electrical and optical characteristics, all products are inspected for following 3 items.

Forward Voltage :  $V_F$ Reverse Current :  $I_R$ Radiant Intensity : le

7-2. No particular inspections shall be carried out for items other than those above.

However they shall satisfy the ratings.

<sup>\*2.</sup> No Icebound or dew

<sup>\*3.</sup> For Max.5seconds at the position of 2mm from the package



## 8. Caution On Usage

- 8-1. Store and use where there is no exterior force that will cause change in shape etc.
- 8-2. Store and use where is no Hydrogen Sulfide gas, or any other corrosive gas.
- 8-3. The bending or cutting of the lead should be done in room temperature and no force applied on the package.
- 8-4. Solder the lead pin under the conditions of the characteristics chart, and do not apply force on the lead pin after soldering.

#### 9. Guarantee Period And Scope

- 9-1. Period
  - 1 year after shipment to desired place.
- 9-2. Scope

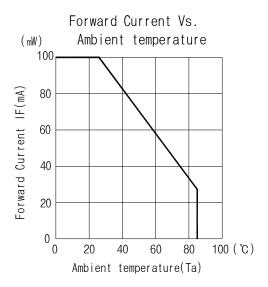
A replacement of products will be carried out if the problem lies in our company's product. However, we are not liable for your damage due to lack of caution.

#### 10. Others

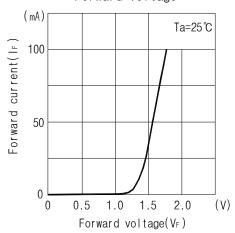
10-1. Any doubts concerning this specification should be discussed fully by both parties.



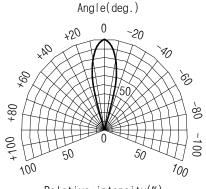
#### 11. Technical Characteristics



Forward current Vs. Forward voltage



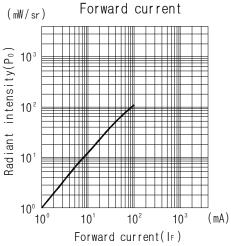




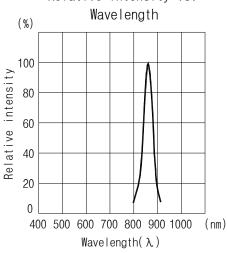
Relative intensity(%)

### **Attachment**

Relative intensity Vs.



Relative intensity Vs.



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